Subband Structure of a Two-Dimensional Electron Gas Formed at the Polar Surface of the Strong Spin-Orbit Perovskite KTaO₃

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We demonstrate the formation of a two-dimensional electron gas (2DEG) at the (100) surface of the 5dtransition-metal oxide KTaO₃. From angle-resolved photoemission, we find that quantum confinement lifts the orbital degeneracy of the bulk band structure and leads to a 2DEG composed of ladders of subband states of both light and heavy carriers. Despite the strong spin-orbit coupling, our measurements provide a direct upper bound for the potential Rashba spin splitting of only $\Delta k_{\parallel} \sim 0.02$ Å⁻¹ at the Fermi level. The polar nature of the $KTaO_3(100)$ surface appears to help mediate the formation of the 2DEG as compared to nonpolar $SrTiO_3(100)$.

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Today's electronic devices largely rely on the tunability of narrow conducting channels in semiconductor hosts. Creating such two-dimensional electron gases (2DEGs) in oxides, which in bulk form generally show much larger and more diverse responses to external stimuli, holds the potential for devices with functionalities well beyond what we have experienced to date [1,2]. The prototypical oxide 2DEG is formed when SrTiO₃ is interfaced to the polar surface of another perovskite oxide [3]. This system indeed shows novel properties [2,4], such as an unusual coexistence of ferromagnetism and superconductivity [5,6]. Several combinations of ABO₃/SrTiO₃ heterostructures have been investigated to date, incorporating both Mott [7] and band insulators [3,8] as the overlayer. However, the 2DEGs formed were always found to reside in SrTiO₃. There is great current interest in inducing 2DEGs in more exotic parent materials [9]. The recent discovery that oxygen vacancies mediate the formation of a 2DEG at the bare surface of SrTiO₃ [10,11] may provide a route to achieve this.

Of particular interest are 5d transition-metal oxides (TMOs). Their large spin-orbit interactions are thought to drive the formation of a host of unconventional ground states such as J = 1/2 Mott insulators [12,13], correlated topological insulators [14-16], and spin-triplet superconductors [17]. Moreover, 5d TMOs offer the potential to incorporate the spintronic functionality sought in emerging schemes of semiconductor electronics [18-20] into alloxide devices. They could therefore provide a novel and potentially very rich host for the engineering of artificial 2D electron systems. Understanding the interplay of strong spin-orbit coupling, quantum confinement, and electronic correlations within such a 2DEG is an essential step towards realizing their potential for practical applications. To date, however, this has been hampered by the difficulty of generating 2DEGs localized in 5d oxides via interface engineering.

Here, we show that such a 2DEG can be created at the (100) surface of the 5d perovskite $KTaO_3$. We utilize angle-resolved photoemission (ARPES) to provide the first direct measurement of the subband structure of a 5d oxide 2DEG. Our model calculations are in agreement with ARPES measurements of both SrTiO₃ and KTaO₃ 2DEGs, strongly constraining theoretical pictures of such systems. In particular, we find a delicate interplay of multiorbital physics, quantum confinement, and spin-orbit interactions, driving orbital ordering within the 2DEG. Surprisingly, however, the 2DEG does not exhibit the large Rashba spin splitting which might naturally be expected.

Single-crystal undoped KTaO₃ (commercial samples from Crystal Base, Japan) and lightly electron-doped $K_{1-x}Ba_xTaO_3$ (flux-grown samples, x < 0.001) were measured. The Ba doping yields a small residual bulk conductivity ($n \sim 1 \times 10^{19}$ cm⁻³ from Hall effect measurements) which eliminates charging effects in ARPES but does not otherwise affect the conclusions of this Letter. ARPES measurements (T = 20 K, $h\nu = 45-85$ eV) were performed using Scienta R4000 hemispherical analyzers at beam line 10.0.1 of the Advanced Light Source and the SIS beam line of the Swiss Light Source, with an energy resolution between 8 and 35 meV and an angular resolution of 0.35°. Multiple samples were cleaved along the (100) surface at the measurement temperature in a pressure better than 3×10^{-11} mbar. Preliminary *in situ* transport measurements performed at beam line 3.2a of the Synchrotron Light Research Institute (SLRI), Thailand, support the conclusions drawn from our ARPES work.

Our surface-sensitive ARPES measurements (Fig. 1) reveal a complex electronic structure with at least 4 dispersive electronlike bands which cross the chemical potential [Figs. 1(a) and 1(b)]. This directly indicates that the surface of this material has become strongly conducting, in contrast to its bulk. We note that these measurements were performed at a photon energy chosen to probe electronic states near to the Brillouin zone boundary along k_z , where no bulk bands are expected in the vicinity of the Fermi level. Moreover, the same states are observed for both lightly bulk-doped and insulating undoped KTaO₃ samples (not shown). These states have equal Fermi wave vectors and occupied bandwidth (within our experimental resolution), even though the bulk carrier density should vary by at least 5 orders of magnitude between the samples. This



conclusively rules out bulk states as the source of the measured bands. Photon-energy-dependent measurements (not shown) further reveal that the observed states have no dispersion along k_z . They are therefore two-dimensional electronic states confined near the surface, unlike the three-dimensional bulk states.

After cleaving the sample, and upon exposure to intense UV light, the Fermi wave vectors of the states increase [Fig. 2(a)] and then saturate to give the electronic structure shown in Fig. 1. At the same time, the O 2p valence bands shift to higher binding energy [Fig. 2(b)], indicating a downward bending of the valence and conduction bands relative to the Fermi level in the vicinity of the surface. This causes a buildup of charge near the surface [21]. In conventional semiconductors, these electrons do not occupy the original bulk electronic states: the electrostatic band bending potential, together with the potential step at the surface itself, forms a quantum well. This causes the conduction bands to reconstruct into ladders of partially filled two-dimensional subbands [22]. The twodimensional metallic states that we measure here by ARPES are the first direct observation of such quantumconfined states in a 5d TMO. The formation of the 2DEG is accompanied by the emergence of an in-gap defect peak $[V_{0} \text{ in the inset of Fig. 2(b)}]$, indicative of oxygen vacancies at the surface. This suggests that the density of the 2DEG in KTaO₃ may be tuned by controlling the positive surface charge resulting from a UV-stimulated desorption of oxygen, as recently found for a surface 2DEG created in SrTiO₃ [10].

However, unlike in $SrTiO_3$, the 2DEG in $KTaO_3$ exists right from the initial stages of our measurement [Fig. 2(a)]. This is most likely due to the polar nature of $KTaO_3(100)$. In order to avoid the large energy cost associated with a



FIG. 1 (color online). (a),(b) ARPES measurements of the Γ -X dispersion of surface 2DEG states in KTaO₃, measured using *p*-and *s*-polarized 55 eV synchrotron light around the Γ_{11} and Γ_{10} points, respectively. A schematic representation of the measured band structure is shown in the insets. (c),(d) Equivalent measurements of the Fermi surface.

FIG. 2 (color online). (a) Irradiation dose dependence of the Fermi wave vector of the deepest d_{xy} -type band of surface 2DEGs formed in SrTiO₃ and KTaO₃ upon exposure to intense UV light, normalized to their saturation values. A low-energy electron diffraction image of KTaO₃, taken after UV light exposure, is shown in the inset. (b) O 2*p* valence bands of KTaO₃ after small and heavier irradiation doses, with the near- E_F emission magnified in the inset.

polar catastrophe, KTaO₃ likely cleaves, leaving approximately half a $(KO)^{-}$ layer on the $(TaO_2)^{+}$ surface. This structural arrangement may lower the formation energy for oxygen vacancies compared to $SrTiO_3(100)$, allowing much more rapid initial formation of the 2DEG. Alternately, if the surface TaO₂ plane is terminated by less than half a KO layer, the 2DEG could exist directly following the sample cleave in order to screen the intrinsic positive charge associated with the polar surface. Instead of the creation of oxygen vacancies, the increase in 2DEG density with irradiation dose could also be associated with the desorption of $(KO)^{-}$ from the surface. This would drive the system back towards an ideal polar surface. Intriguingly, from a comparison of model calculations (discussed below) to the ARPES measurements, we estimate the saturated density of the 2DEG to be $N \approx 2 \times$ 10^{14} cm⁻², which is slightly lower than, but approaching, the $0.5e^{-}$ per unit cell $(3.3 \times 10^{14} \text{ cm}^{-2})$ which would be expected from a simple polar catastrophe argument [23] for a stoichiometric TaO₂ surface. Thus, while an interface between a polar and nonpolar surface does not always appear necessary to create an oxide 2DEG [10,11], these measurements suggest that it may help mediate its formation, either via intrinsic electronic reconstruction [23] or by promoting the formation of extrinsic defects. We note that (1×1) low-energy electron diffraction patterns were observed both before and after UV irradiation [see the inset to Fig. 2(a)], indicating that changes of the 2DEG are not driven by surface reconstruction of the cleaved KTaO₃ crystals.

The two highest binding energy bands of the resulting 2DEG [bands 1 and 2, Fig. 1(a)] have a light effective mass of $\sim 0.3 m_e$ [24], obtained from parabolic fits to their measured dispersion. This is almost a factor of 2 smaller than recently determined for a surface 2DEG in SrTiO₃ [10], suggesting that KTaO₃ could provide a superior platform to its workhorse counterpart of SrTiO₃ with which to develop high-mobility oxide electronics. We also observe a tail of intensity below the band bottom of these states, characteristic of the spectral function in strongly interacting systems. This hints at an important role of electron correlations in this system, signifying a liquidlike state, as was recently inferred for 2DEGs at SrTiO₃ surfaces and interfaces [10,25]. Thus, KTaO₃-based 2DEGs may provide an appealing route to combine the exotic phase diagrams that often accompany strong electron correlations with a system which supports very mobile carriers, useful for device applications. In this respect, we note that a record mobility for a TMO 2DEG of 7000 cm² V⁻¹ s⁻¹ was recently achieved in a KTaO₃ electric double-layer transistor [26]. The same system was also found to superconduct, a property which has not to date been obtained in the bulk of this material.

Coexisting with these mobile states, we additionally observe much heavier carriers (bands 3 and 4 in Fig. 1(b)

, $m^* \sim 2-3m_e$). Together, the light and heavy mass bands contribute both concentric circular [Fig. 1(c)] as well as elliptical [Fig. 1(d)] electron pockets to the Fermi surface, suggesting that the electronic structure observed here is derived from multiple orbitals of different symmetries. Indeed, the bulk conduction bands of KTaO₃, as in $\mathrm{SrTiO}_3,$ are formed from three t_{2g} orbitals [27]. In the simplest picture, these form three d_{xy} -, d_{xz} -, and d_{yz} -derived interpenetrating ellipsoids, giving rise to one heavy and two light bands along the $\langle 100 \rangle$ directions [Fig. 3(a)]. However, spin-orbit coupling in KTaO₃ leads to a strong orbital hybridization. As shown in Fig. 3(b), this lifts the Γ -point degeneracy by splitting off a light band above a pair of light and heavy bands by a large energy gap of $\Delta_{so} \sim 400$ meV. The electronic bands we observe, however, have quite different characteristics (Fig. 1), with at least two light bands located at higher binding energies than the first heavy state.

In the following, we show that this can be attributed to a modification of the orbital occupancy due to quantum confinement. We start by discussing the simpler case of a



FIG. 3 (color online). Local-density approximation (LDA) calculations of the bulk electronic structure and orbital character of KTaO₃ (a) excluding and (b) including spin-orbit coupling. (c) Comparison of measured dispersions to model tight-binding calculations of a surface 2DEG in SrTiO₃. (d) Equivalent calculations for a KTaO₃ 2DEG, including the strong spin-orbit coupling. The colored lines give a schematic decomposition of its orbital makeup. (e) Comparison of the KTaO₃ calculations to the experimental data from Figs. 1(a) and 1(b).

SrTiO₃ surface 2DEG [Fig. 3(c)], where the spin-orbit split-off energy is small and can be neglected to first approximation [28]. We model the electronic structure using a tight-binding supercell with band bending included via additional on-site potential terms, similar to the method introduced by Stengel [30]. This model is solved self-consistently with Poisson's equation, incorporating an electric-field-dependent dielectric constant [31], to yield the electronic structure shown in Fig. 3(c).

Starting at the highest binding energies, a ladder of multiple d_{xy} -derived subbands is predicted. These are in good agreement with the multiple light states observed by ARPES [Fig. 3(c)]. This orbital assignment is consistent with their circular Fermi surfaces [10] and with the ladder of isotropic states recently observed in quantum oscillation measurements of δ -doped SrTiO₃ quantum wells [32,33]. Because of the small interlayer hopping between d_{xy} orbitals along the confinement direction, or equivalently their heavy effective mass along k_z , the most deeply bound of these subbands have wave functions which are dominantly localized on successive atomic planes below the surface, explaining why they can be clearly observed in ARPES [34].

On the other hand, the $d_{xz/yz}$ orbitals have a significantly larger overlap along k_z , leading to a much lighter effective mass along this direction. The binding energy of the heavy and light pairs of $d_{xz/yz}$ -derived subbands is correspondingly reduced [11], lifting the orbital degeneracy of the bulk band structure [35]. This effect can be seen in our measurements, where a heavy band, whose binding energy and dispersion are in good agreement with the calculated d_{xz} -derived subband, can just be resolved in the normalized spectrum shown in Fig. 3(c). Their reduced confinement energy results in subbands with envelope wave functions which are much more extended along k_z than for the lower d_{xy} bands, explaining the very weak spectral weight of the heavy bands in our measurements. The quantitative agreement of these calculations with the ARPES data confirms that the 2DEG in SrTiO₃ is generated by a near-surface band bending. This strongly supports first-principles calculations for the LaAlO₃/SrTiO₃ interface system that similarly find multiple coexisting confined and extended states within the 2DEG [36] and constrains theoretical models of orbital ordering and degeneracy in these systems.

Our calculations can be readily adapted to KTaO₃, as shown in Fig. 3(d) [37]. These can be qualitatively understood starting from the same orbital makeup as in SrTiO₃, but with some important additional features. (1) The lighter of the original $d_{xz/yz}$ -derived states is shifted above the Fermi level by the large spin-orbit split-off energy, Δ_{so} . This lifts the Γ -point degeneracy of $d_{xz/yz}$ states that is present for SrTiO₃. (2) Small hybridization gaps open up between the different subbands. (3) The orbital character of the lighter bands becomes strongly mixed. These characteristics are fully consistent with the measured band structure shown in Fig. 3(e), although some of the more subtle features of the calculations cannot easily be resolved experimentally.

The calculations also predict a small spin splitting of the 2DEG states around the hybridization gaps [Figs. 3(d) and 3(e)]. This can be attributed to the Rashba effect, which lifts spin degeneracy in the presence of a structural inversion asymmetry [39]. The symmetry breaking is provided here by the asymmetric potential well which confines the 2DEG. However, despite the strong spin-orbit interactions, the calculated spin splitting Δk_{\parallel} is only ~0.01 Å⁻¹ at the Fermi level. This is almost an order of magnitude smaller than recently observed for the seemingly similar system of a 2DEG in the heavy Bi-containing topological insulator Bi₂Se₃ [40], despite the much larger near-surface potential gradient confining the KTaO₃ 2DEG. We note, however, that a small Rashba splitting of 0.01 \AA^{-1} is consistent with spin precession lengths extracted from weak antilocalization measurements of a KTaO₃ field-effect transistor [41]. This is also consistent with our experimental data, where any Rashba splitting is too small to be resolved, placing a direct, model-independent, upper bound of ~ 0.02 Å⁻¹ for spin splitting at the Fermi level.

We attribute the small magnitude of the spin splitting to the particular electronic states involved: the degenerate t_{2g} manifold of states at Γ is split into an effective J = 3/2doublet at the conduction band edge and a J = 1/2 splitoff band [Fig. 3(b)] [12]. This is analogous to the valence, rather than conduction, bands of typical III–V semiconductors such as GaAs. In such systems, the *k* linear term in the Rashba spin splitting of a 2D hole gas is forbidden due to symmetry, leaving the leading-order term as k^3 [42]. In the low-*k* regime applicable here, this yields a very small Rashba splitting, even with the strong spin-orbit coupling and large potential gradient within the 2DEG.

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